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Defect Induced Ferromagnetism in Undoped ZnO Nanoparticles

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Defect induced ferromagnetism in undoped ZnO nanoparticles

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Undoped ZnO nanoparticles (NPs) with size ~12 nm were produced using forced hydrolysis methods using diethylene glycol (DEG) [called ZnO-I] or denatured ethanol [called ZnO-II] as the reaction solvent; both using Zn acetate dehydrate as precursor. Both samples showed weak ferromagnetic behavior at 300 K with saturation magnetization \( M_s = 0.077 \pm 0.002 \) memu/g and \( 0.088 \pm 0.013 \) memu/g for ZnO-I and ZnO-II samples, respectively. Fourier transform infrared (FTIR) spectra showed that ZnO-I nanocrystals had DEG fragments linked to their surface. Photoluminescence (PL) data showed a broad emission near 500 nm for ZnO-II which is absent in the ZnO-I samples, presumably due to the blocking of surface traps by the capping molecules. Intentional oxygen vacancies created in the ZnO-I NPs by annealing at 450 °C in flowing Ar gas gradually increased \( M_s \) up to 90 min and x-ray photoelectron spectra (XPS) suggested that oxygen vacancies may have a key role in the observed changes in \( M_s \). Finally, PL spectra of ZnO showed the appearance of a blue/violet emission, attributed to Zn interstitials, whose intensity changes with annealing time, similar to the trend seen for \( M_s \). The observed variation in the magnetization of ZnO NP with increasing Ar annealing time seems to depend on the changes in the number of Zn interstitials and oxygen vacancies.

Zinc Oxide (ZnO) nanoparticles (NPs) have been a large focus in materials research. Because of their small size, NPs of many oxide materials such as ZnO display novel properties, including room temperature ferromagnetism (RTFM). Various types of lattice defects, including oxygen vacancies, metal interstitials, and metal vacancies, have been proposed as the source of the RTFM in undoped oxide nanoparticles.2,3 However, clear evidence on the role of surface defects on this unusual ferromagnetism in undoped oxide NP is lacking. To investigate the role and type of defects contributing to the RTFM of ZnO NPs, their magnetic behavior is investigated as a function of defects introduced intentionally by annealing in Ar atmosphere at 450 °C.

All undoped ZnO NPs used in this study were produced using one of two forced hydrolysis methods, both using Zn acetate dehydrate as precursor, with DEG (referred to as ZnO-I) or denatured ethanol (ZnO-II) as the reaction solvent. Details of their synthesis and characterization are discussed in Ref. 4.

As prepared samples were annealed in the 200–750 °C range in Ar atmosphere (flow rate 20 ml/min) using a Netzsch Simultaneous Thermal Analysis (STA) 449 F1, capable of monitoring both mass and energy changes. This STA unit was used in combination with a quadrupole mass spectrometer (QMS) evolved gas analysis system to monitor elemental and molecular burn-off. It was determined that 450 °C was the optimal temperature to remove organic precursors while causing the least grain growth. Samples were annealed at 450 °C for varying amounts of time (30, 45, 60, 75, 90, and 120 min). The as-prepared and annealed samples were analyzed using x-ray diffraction (XRD), XPS, vibrating sample magnetometry (VSM), FTIR, and low temperature (~10 K) photoluminescence (PL) and Raman spectra (with a 325 nm UV excitation) following procedures described elsewhere.4 These studies confirmed the absence of contamination in samples.

XRD patterns confirm the samples to be single phase wurtzite ZnO with no detectable secondary phases. Lattice parameters and crystallite size determined using Rietveld refinement methods revealed an average crystallite size of 12.3 ± 0.35 nm for ZnO-I and ZnO-II. Lattice parameters were around \( a = 3.25 \pm 0.0003 \) Å and \( c = 5.21 \pm 0.003 \) Å for the as-prepared and annealed samples. Samples displayed growth up to ~29 nm when the NPs were annealed at 450 °C, attributed to the expected sintering process.

The FTIR spectra of ZnO-I and ZnO-II are shown in Figs. 1(a) and 1(b). The data showed the major characteristic Zn-O vibrations5 at 478 cm\(^{-1}\) in ZnO-I and 444 cm\(^{-1}\) in ZnO-II. The broad absorptions around 3410–3420 cm\(^{-1}\) due to hydroxyl groups are relatively stronger in ZnO-I. Presence of fragments of DEG is observed in ZnO-I NP. No such surfactant layer is present on ZnO-II NP. The ZnO-I sample exhibits two strong bands, commonly associated with the carboxylate functional group, at 1412 cm\(^{-1}\) [\( \nu (\text{COO}^-) \)] and 1595 cm\(^{-1}\) [\( \nu (\text{COO}^-) \)].5,7 Additionally, weaker bands consistent with \( \nu (\text{CH}_2) \) and \( \nu (\text{C}=\text{O}) \) at 907 and 1067 cm\(^{-1}\) are also observed.6,8 ZnO-II also showed many of these bands due to surface adsorbed groups resulting from the acetate groups, but with somewhat lower intensity and at slightly different frequencies, presumably due to the absence of a surfactant like DEG in this sample.

The PL spectra of the samples recorded at 10 K using a 325 nm He:Cd laser are shown in Figures 1(c) and 1(d).
Higher order Raman peaks appear in the spectra caused by resonance Raman scattering due to the band gap approaching the excitation laser line. The UV emission band at ~3.37 eV can be explained by a near band-edge transition of wide band gap ZnO NPs, the free exciton recombination through an exciton–exciton collision process. It has been theoretically proposed that the position of the Zn interstitials (Zni) in the ZnO band structure is about 0.22 eV below the conduction band. So a radiative transition from the acceptor states due to such Zn to the valence band will result in a blue/violet emission in the 400–450 nm range. Energy levels corresponding to oxygen interstitial (Oi) and oxygen vacancy (Vo) are located at 2.28 eV and 1.85 below the conduction band. Orange-red emissions centered at ~600–700 nm are generally attributed to deep level defects such as vacancies and interstitials of oxygen. These orange-red emissions are experimentally observed in oxygen-rich sample suggesting that Oi may be the dominant player. Green emission is most likely due to oxygen vacancies. In oxygen deficient samples, both oxygen vacancies and zinc interstitials might exist as potential defects. The oxygen vacancies can form two types of defect states: a shallow donor level and a deep donor level. While the shallow donor level is very close to the conduction band, the deep donor level is ~0.7–0.8 eV below the conduction band. The energy difference between the deep donor level and the top of the valence band is about 2.43–2.53 eV, and this is consistent with the green emission energy. Zinc interstitials also can be formed in zinc-rich samples, which can act as electron donors. Both oxygen vacancies and zinc interstitials have low formation energies, but oxygen vacancies are expected to be the dominant defects in nanoparticles due to their large surface to volume. According to the existing models, surface sites are proposed to be responsible for all non-excitonic relaxation processes in NPs. There are two potential relaxation processes proposed in these models. In one case, a hole from the valence band can be trapped by surface O2− sites, thus producing O− sites. A green emission can occur if the hole tunnels the singly ionized oxygen vacancy in the neighborhood.

Another possibility is that an electron from the conduction band gets trapped on a surface O2− to become O2−. A green emission can occur if this O2− traps a hole.

Thus, the as-prepared ZnO-II NP with large green emission might have large number of oxygen vacancies. Annealing it in Argon atmosphere at 450 °C for 1 h produces a new blue/violet emission centered at 416 nm. It seems that the blue/violet emission and the exciton emission increased in intensity at the expense of green emission (Figures 1(c) and 1(d)). It appears that the annealing process in Ar atmosphere produced a Zn-rich sample with large number of Zni to generate the blue/violet emission. Increased number of carriers or larger crystallite size due to sintering might have enhanced exciton emission also. Further increase in the annealing time to 2 h reduced the green emission while the intensity of the exciton emission increased significantly. The blue/violet emission intensity also somewhat decreased. Interestingly, the ZnO-I NPs prepared using DEG did not show any of the visible emissions and no significant change in the intensity of the exciton emission was observed. The FTIR data clearly showed that DEG molecules are present on the NP surface. Note that O2− surface trap in ZnO nanocrystals are actually OH- which is also seen in the FTIR data. Capping ZnO-I nanocrystals with organic molecules such as DEG might have removed the surface hole traps. Absence of both green and blue/violet emissions in this samples indicates that both these emissions are related to surface structure/defects.

Magnetization (M) of the NPs as a function of applied magnetic field (H) was measured over the range of ±1 T. A diamagnetic susceptibility, \( \chi = -7.438 \times 10^{-8} \text{emu/Oe} \), from the straw was subtracted from all data. All samples showed a weak ferromagnetic component with open hysteresis loops at room temperature, superimposed on an overall paramagnetic signal. The saturation magnetization (Ms) of the as-prepared ZnO-II had a slightly higher Ms of 0.088 ± 0.013 memu/g compared to 0.077 ± 0.002 memu/g. Interestingly, the Ms values follow a clear trend in both samples as shown in Figure 2(a). Ms gradually increases with annealing time, reaching a maximum after 75 min of annealing, followed by a decrease for 120 min.

The binding energy (BE) of Zn 2p3/2 peak of the as-prepared and annealed samples is centered around 1021.2–1021.5 eV, with a spin-orbit splitting (AS) of 23.1 eV, as expected for Zn2+ ions. The O 1s spectra showed broad asymmetric features, which were fitted by two components, indicating the presence of two different sources of oxygen ions with different chemical environments in both as-prepared as well as annealed ZnO samples. The relatively stronger component on the lower binding energy side, in the range of 530.2–529.9 eV, can be attributed to O2− ions on the wurtzite structure surrounded by Zn2+ atoms in tetrahedral sites, located mainly in the core region of the NPs. As annealing time increased from 0 to 120 min, the BE showed a systematic increase from 529.69 to 529.79 eV. This might be the result of increasing formation of oxygen vacancies or Zn interstitials. The second O 1s peak was observed at 531.1–531.6 eV is ascribed to oxygen ions on the surface region of the NP, probably related to -OH groups.
Chemisorbed on the surface, as observed in FTIR data also, indicating the presence of loosely bound oxygen near the surface region of ZnO nanoparticles. Changes in this component may be related to changes in the concentration of oxygen vacancies and/or oxygen interstitials on the surface of ZnO NPs. As annealing time increased from 0 to 120 min, area of the larger peak (×1021 eV) increased from 62.2% to 72% while that of the smaller peak (×1044 eV) decreased from 37.8% to 28%. Furthermore, with increasing annealing time, the smaller peak showed a systematic shift from 531.13 to 531.45 eV. These gradual changes in intensity and peak position suggest that annealing in Ar leads to more oxygen vacancies in the surface region of the NPs, while at the same time, in the core of the nanocrystals, this process might have filled any oxygen vacancies and possibly introduced some oxygen interstitials too.

FIG. 2. (a) Trend in $M_s$ of annealed ZnO-I (black squares; left y-axis) and annealed ZnO-II (red circles; right y-axis) as a function of annealing time. (b) Ratio of Zn 2p area to O 1s and $M_s$ trend of ZnO-II with annealing time.

What is responsible for the observed RTFM in undoped ZnO? Weak RTFM is observed in the as-prepared ZnO NPs. As shown in Fig. 2, $M_s$ increased significantly after 1 h of annealing in Ar and then it decreases when annealed for 2 h. The same trend is observed in both ZnO-I and ZnO-II samples. Role of oxygen vacancies in the magnetic behavior of ZnO NPs is indicated from the XPS data (Figure 2(b)). Absence of capping molecules in ZnO-II allows it to emit green presumably due to the presence of large number of oxygen vacancies. However, its intensity decreases with increasing Ar annealing time and a blue/violet emission starts appearing, suggesting significant changes in the defect composition and the formation of more Zn$_i$. The observed changes in the intensity of the blue/violet emission correlate with the observed variation of $M_s$, suggesting that Zn$_i$ may also be a key player in the observed magnetic properties of ZnO NPs. It seems that the blue emission grows at the expense of green emission, indicating that the processes that create Zn$_i$ and V$_o$ may be related.

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